

CMSP3139KT-HF

P-Channel
RoHS Device
Halogen Free



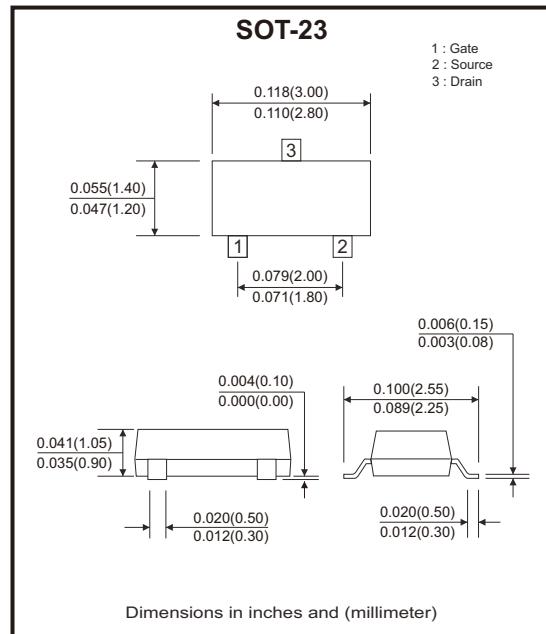
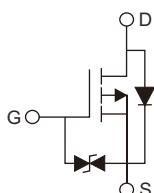
Features

- Surface mount package.
- P-Channel switch with Low RDS(on).
- Operated at low logic level gate drive.

Mechanical data

- Case: SOT-23, molded plastic.
- Mounting position: Any.

Circuit Diagram



Maximum Ratings (at Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V _{DS}	-20	V
Typical gate-source voltage	V _{GS}	±12	V
Continuous drain current (Note 1)	I _D	-0.66	A
Pulsed drain current @tp=10µs	I _{DM}	-1.2	A
Power dissipation (Note 1)	P _D	350	mW
Thermal resistance, junction to ambient (Note 1)	R _{θJA}	357	°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150	°C
Lead temperature for soldering purpose (1/8" duration for 10s)	T _L	260	°C

Electrical Characteristics (at $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Static characteristics						
Drain-source breakdown voltage	BV_{DSS}	$V_{\text{GS}} = 0\text{V}, I_{\text{D}} = -250\mu\text{A}$	-20			V
Zero gate voltage drain current	I_{DSS}	$V_{\text{DS}} = -20\text{V}, V_{\text{GS}} = 0\text{V}$			-1	μA
Gate-body leakage current	I_{GSS}	$V_{\text{GS}} = \pm 10\text{V}, V_{\text{DS}} = 0\text{V}$			± 20	μA
Gate threshold voltage (Note 2)	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = -250\mu\text{A}$	-0.35	-0.45	-1.1	V
Drain-source on-state resistance (Note 2)	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -4.5\text{V}, I_{\text{D}} = -1\text{A}$		430	520	$\text{m}\Omega$
		$V_{\text{GS}} = -2.5\text{V}, I_{\text{D}} = -0.8\text{A}$		624	700	
		$V_{\text{GS}} = -1.8\text{V}, I_{\text{D}} = -0.5\text{A}$		950		
Forward transconductance (Note 2)	g_{fs}	$V_{\text{DS}} = -10\text{V}, I_{\text{D}} = -0.54\text{A}$		1.2		S
Drain forward voltage	V_{SD}	$I_{\text{S}} = -0.5\text{A}, V_{\text{GS}} = 0\text{V}$			-1.2	V
Dynamic characteristics (Note 4)						
Input capacitance	C_{iss}	$V_{\text{DS}} = -16\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		113	170	pF
Output capacitance	C_{oss}			15	25	
Reverse transfer capacitance	C_{rss}			9	15	
Switching characteristics (Note 4)						
Turn-on delay time (Note 3)	$t_{\text{d}(\text{on})}$	$V_{\text{GS}} = -4.5\text{V}, V_{\text{DS}} = -10\text{V}$ $I_{\text{D}} = -200\text{mA}, R_{\text{GEN}} = 10\Omega$		9		nS
Turn-on rise time (Note 3)	t_{r}			5.8		
Turn-off delay time (Note 3)	$t_{\text{d}(\text{off})}$			32.7		
Turn-off fall time (Note 3)	t_{f}			20.3		

Notes: 1. Surface mounted on FR4 board using the minimum recommended pad size.

2. Pulse width = 300 μs , duty cycle = 2%.

3. Switching characteristics are independent of operating junction temperatures.

4. Guaranteed by design, not subject to production.

Typical Rating and Characteristic Curves (CMSP3139KT-HF)

Fig.1 - Output Characteristics

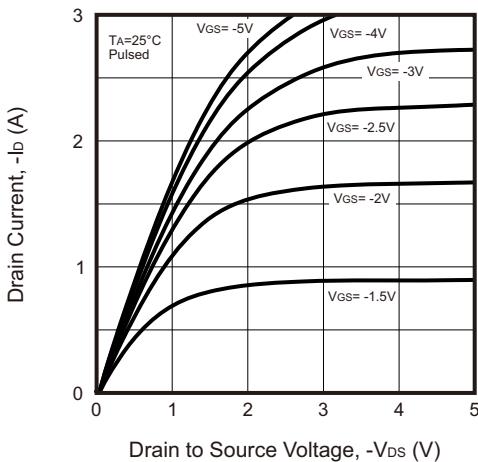


Fig.2 - Transfer Characteristics

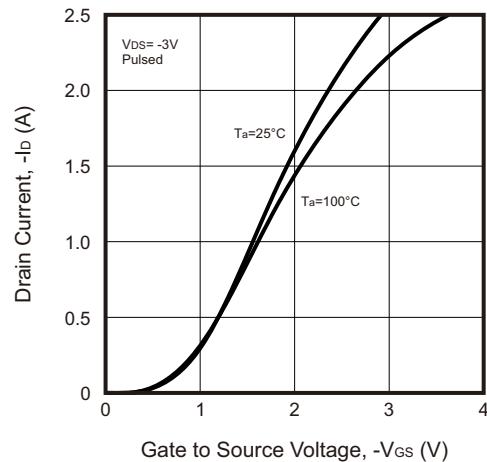


Fig.3 - $R_{DS(ON)}$ — I_D

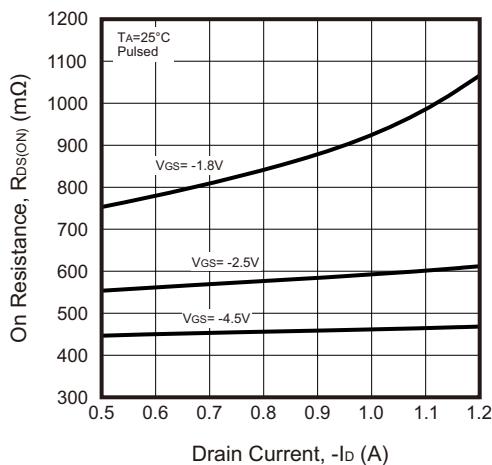


Fig.4 - On-Resistance vs. Gate to Source Voltage

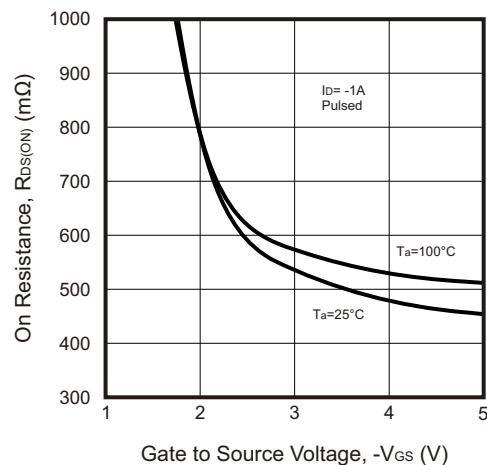


Fig.5 - I_S — V_{SD}

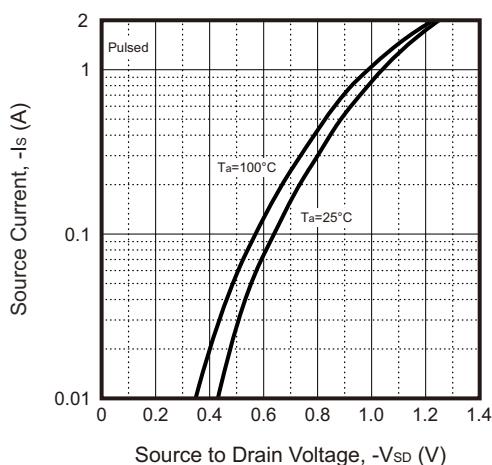
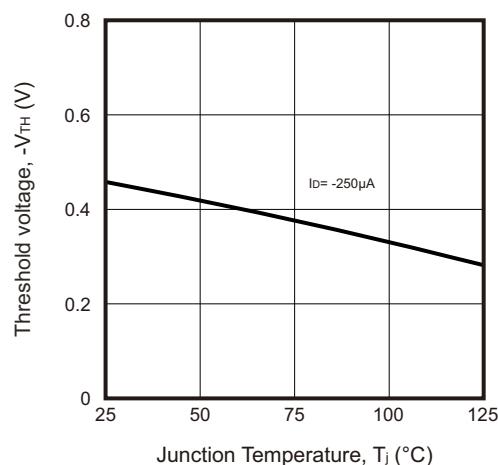
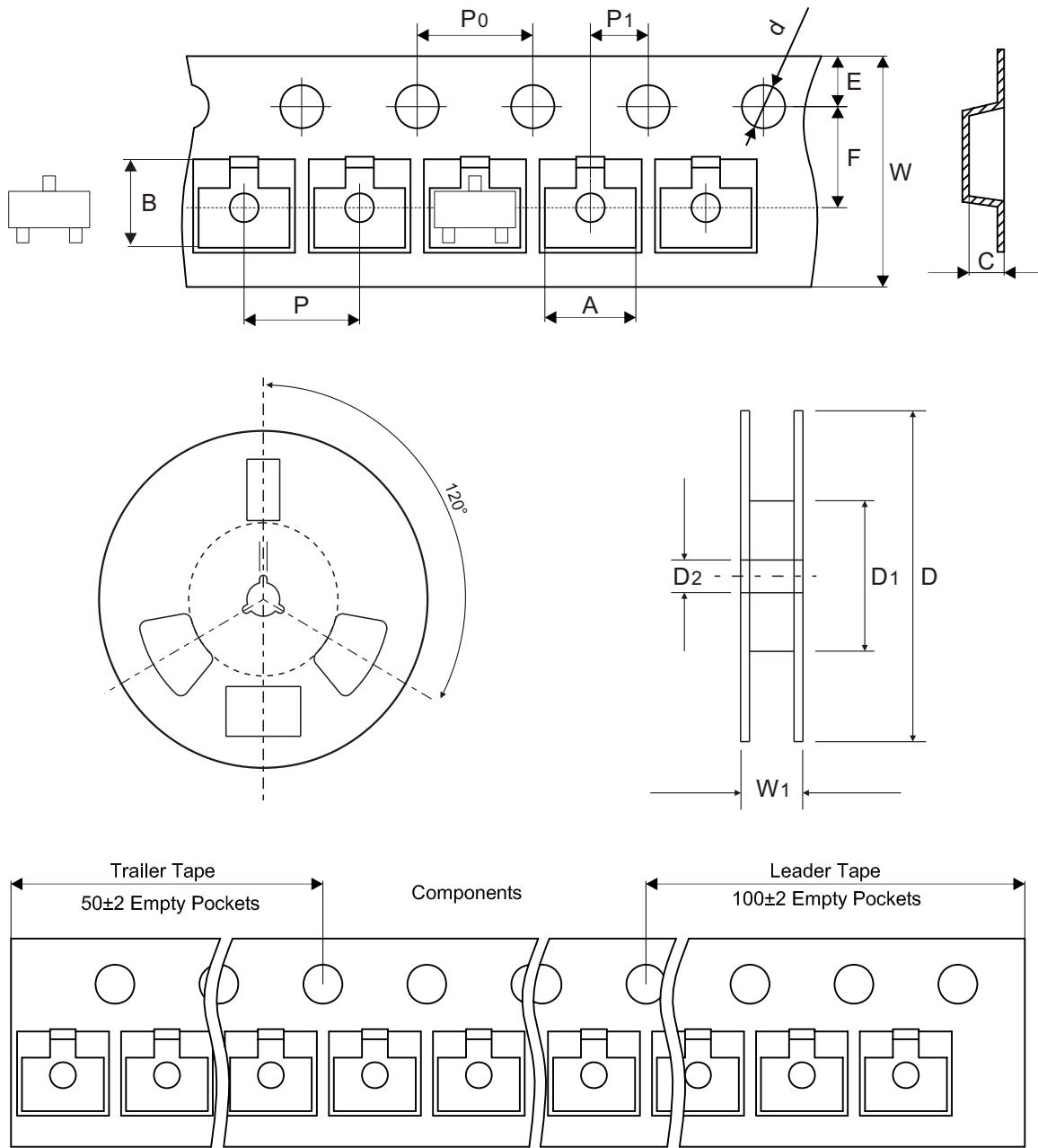


Fig.6 - Threshold Voltage



Reel Taping Specification

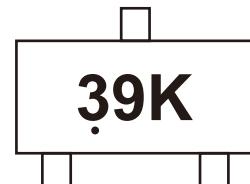


SOT-23	SYMBOL	A	B	C	d	D	D ₁	D ₂
	(mm)	3.15 ± 0.10	2.77 ± 0.10	1.22 ± 0.10	$1.50 + 0.10$ $- 0.00$	178.00 ± 1.00	54.40 ± 0.40	13.00 ± 0.20
	(inch)	0.124 ± 0.004	0.109 ± 0.004	0.048 ± 0.004	$0.059 + 0.004$ $- 0.000$	7.008 ± 0.039	2.142 ± 0.016	0.512 ± 0.008

SOT-23	SYMBOL	E	F	P	P ₀	P ₁	W	W ₁
	(mm)	1.75 ± 0.10	3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	$8.00 + 0.30$ $- 0.10$	12.10 ± 1.00
	(inch)	0.069 ± 0.004	0.138 ± 0.002	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	$0.315 + 0.012$ $- 0.004$	0.476 ± 0.039

Marking Code

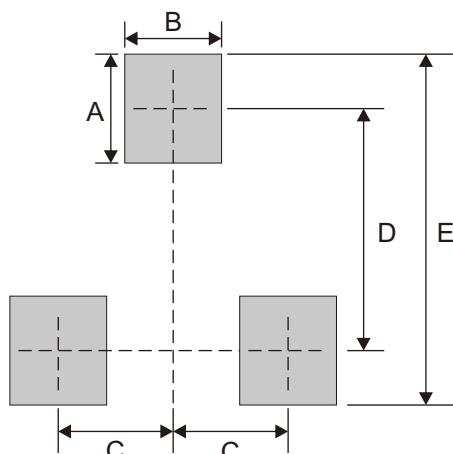
Part Number	Marking Code
CMSP3139KT-HF	39K



Solid dot = Control code

Suggested P.C.B. PAD Layout

SIZE	SOT-23	
	(mm)	(inch)
A	0.90	0.035
B	0.80	0.031
C	0.95	0.037
D	2.00	0.079
E	2.90	0.114



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOT-23	3,000	7